UTC UNISONIC TECHNOLOGIES CO., LTD

J113M1 **N-CHANNEL JFET**

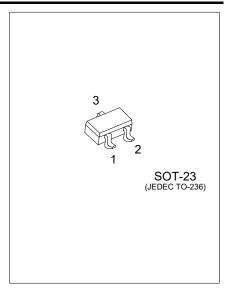
N-CHANNEL SWITCH

DESCRIPTION

The UTC J113M1 is designed for low level analog switching, sample and hold circuits and chopper stabilized amplifiers.

FEATURES

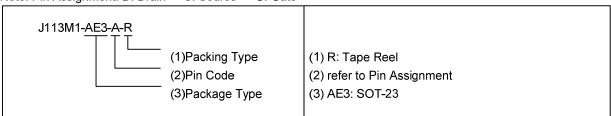
- * MSL1 Robust Package Design
- *Source & Drain are interchangeable.
- * Green & Pb free



ORDERING INFORMATION

Ordering Number	Package	Pin Assignment			Daakina	
		1	2	3	Packing	
J113M1-AE3-R	SOT-23	D	S	G	Tape Reel	
J113M1-AE3-A-R	SOT-23	S	D	G	Tape Reel	

Note: Pin Assignment: D: Drain S: Source G: Gate



MARKING

J113M1	J113M1-A
J113M	113AM

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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATING	UNIT
Drain-Gate Voltage	V_{DG}	35	V
Gate-Source Voltage	V _G s	-30	V
Forward Gate Current	I _{GF}	50	mA
Power Dissipation	P _D	350	mW
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-55 ~ + 150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Ambient	θЈА	357	°C/W
Junction to Case	θ _{JC}	125	°C/W

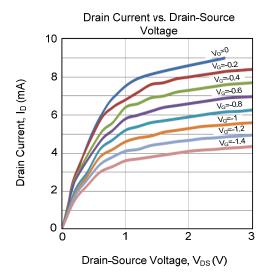
Note: Device mounted on FR-4 PCB 36mm × 18mm × 1.5mm, mounting pad for the collector lead minimum 6cm².

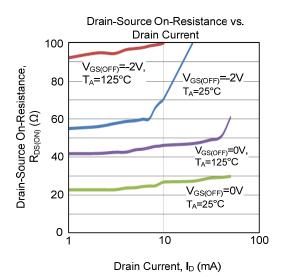
■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

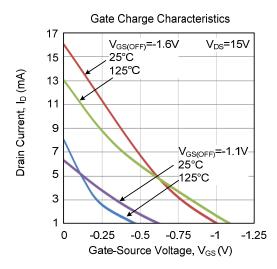
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Gate-Source Breakdown Voltage	$V_{(BR)GSS}$	I _G =-1.0μA, V _{DS} =0	-30			V	
Gate Reverse Current (Note)	Igss	V _{GS} =-15V, V _{DS} =0			-1.0	nA	
Gate-Source Cut-Off Voltage	V _{GS(OFF)}	V _{DS} =15V, I _D =1.0μA	-0.5		-3.0	V	
Drain Cutoff Leakage Current	$I_{D(OFF)}$	V _{DS} =5.0V, V _{GS} =-10V			1.0	nA	
ON CHARACTERISTICS							
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =15V, V _{GS} =0	2.0			mA	
Drain-Source On Resistance	R _{DS(ON)}	V _{DS} ≤0.1V, V _{GS} =0			100	Ω	
SMALL SIGNAL CHARACTERISTICS							
Drain-Gate On Capacitance	C _{DG(ON)}	V _{DS} =0V, V _{GS} =0V, F=1MHz			28	pF	
Source-Gate On Capacitance	Csg(on)	V _{DS} =0V, V _{GS} =0V, F=1MHz			28	pF	

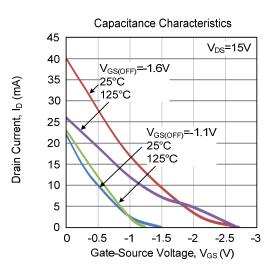
Note: Pulse test: pulse width \leq 300 µs, duty cycle \leq 2%.

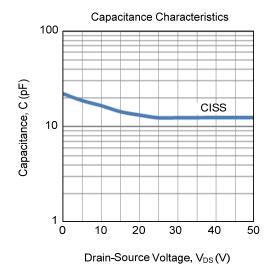
■ TYPICAL CHARACTERISTICS

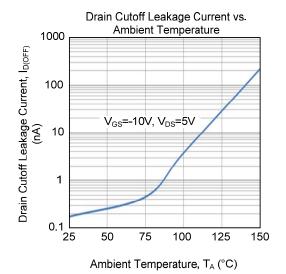












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